Panasonic

PNZ331F (PN331F)

PIN Photodiode

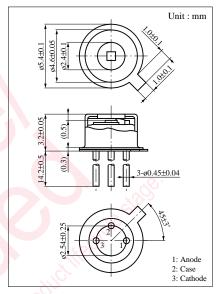
For optical fiber communication systems

Features

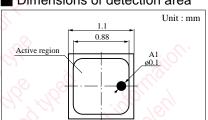
- Metal package with shield pin
- High coupling capability suitable for plastic fiber and glass fiber
- High quantum efficiency
- High-speed response



Parameter	Symbol	Ratings	Unit
Reverse voltage (DC)	V _R	30	V
Power dissipation	P_{D}	50	mW
Operating ambient temperature	T _{opr}	-25 to +100	°C
Storage temperature	T_{stg}	-40 to +100	°C



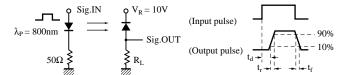
Dimensions of detection area



Electro-Optical Characteristics (Ta = 25°C)

Parameter	Symbol	Conditions	min	typ	max	Unit
Dark current	I_D	$V_R = 10V$	100 p.	0.1	10	nA
Photo current	I_L	$V_R = 10V, L = 1000 lx^{*1}$	4	7		μΑ
Peak sensitivity wavelength	$\lambda_{\rm P}$	$V_R = 10V$		900		nm
Frequency characteristics	f_C^{*2}	$V_R = 10V, R_L = 50\Omega$	00.7	50		MHz
Capacitance between pins	C_{t}	$V_R = 10V$		3		pF
Photodetection sensitivity	R	$V_{R} = 10V, \lambda = 800nm$	0.45	0.55		A/W
Acceptance half angle	θ	Measured from the optical axis to the half power point		40		deg.
Photodetection surface shape	D	Effective photodetection area		□0.88		mm

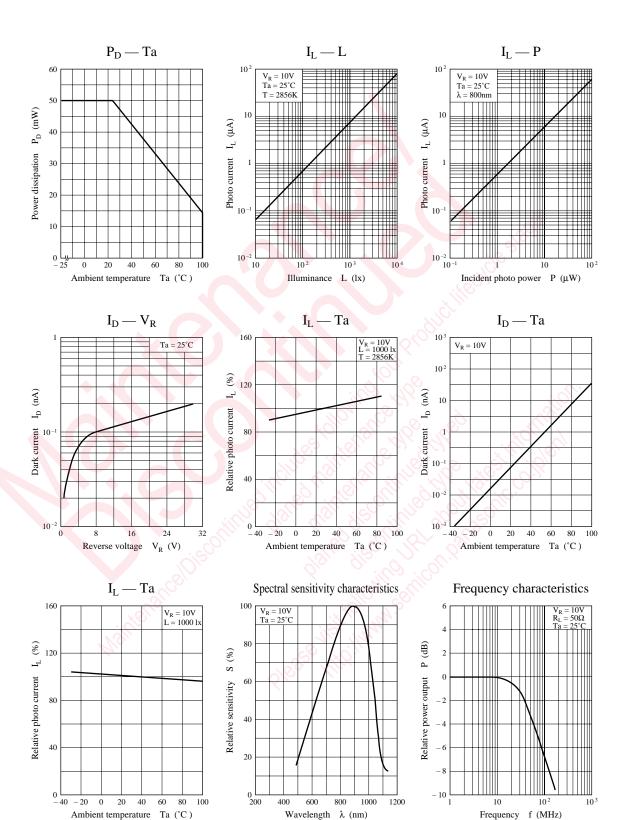
- Note 1) Spectral sensitivity: Sensitivity at wavelengths exceeding 400 nm as a percentage, is 100% to maximum sensitivity.
- Note 2) This product is not designed to withstand electromagnetic radiation or heavy-charge particles.
- Note 3) The glass strength of this product cannot withstand loads of 0.5 kg or greater. This fact needs to be taken into consideration if optical fibers are to be mounted on the product.
- *1 Measurements were made using a tungsten lamp (color temperature T = 2856K) as a light source.
- *2 Switching time measurement circuit (see figure below) Note : Detection photo current -3~dB



- t_d: Delay time
- t_r: Rise time (Time required for the collector photo current to increase from 10% to 90% of its final value)
- $t_{\rm f}$: Fall time (Time required for the collector photo current to decrease from 90% to 10% of its initial value)

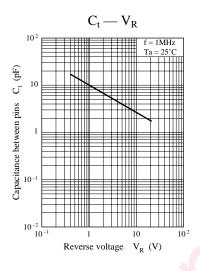
Note) The part number in the parenthesis shows conventional part number.

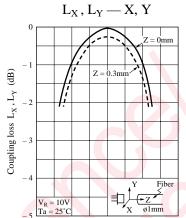
PNZ331F PIN Photodiodes



PIN Photodiodes PNZ331F

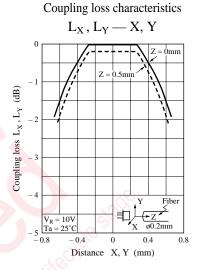
Coupling loss characteristics

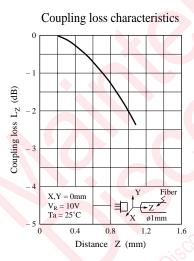


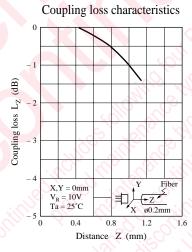


Distance X, Y (mm)

0.8







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